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LM2742 N-Channel FET Synchronous Buck Regulator Controller for Low Output Voltages

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- **Local Regulation of Core Power but adjustable down to 0.6V.**

¹FEATURES DESCRIPTION

² The LM2742 is a high-speed, synchronous, switching **• Input Power from 1V to 16V** regulator controller. It is intended to control currents **•• Output Voltage Adjustable down to 0.6V** of 0.7A to 20A with up to 95% conversion efficiencies.
• **Power Good Flag, Adjustable Soft-start and** only and down sequencing is achieved with the **• Power Good Flag, Adjustable Soft-start and** Power up and down sequencing is achieved with the **Output Enable for Easy Power Sequencing by Power-good flag, adjustable soft-start and output** enable features. The LM2742 operates from a low- **• Reference Accuracy: 1.5% (0°C–125°C)** current 5V bias and can convert from a 1V to 16V **Figurent Limit Without Sense Resistor Figure 10** convert and call convert from a TV to TOV

power rail. The part utilizes a fixed-frequency,

voltage-mode PWM control architecture and the **• Soft Start** voltage-mode, PWM control architecture and the **• Switching Frequency from 50 kHz to 2 MHz** switching frequency is adjustable from 50kHz to 2MHz by setting the value of an external resistor. **•• 40ns Typical Minimum On-time**
Current limit is achieved by monitoring the voltage
drop across the on-resistance of the low-side drop across the on-resistance of the low-side MOSFET, which enables on-times on the order of **APPLICATIONS** 40ns, one of the best in the industry. The wide range **•• POL Power Supply Modules ••** *POL Power Supply Modules ••* *****POL Power Supply Modules ••• POL Power Supply designer the flexibility to fine-tune component size,* **Cable Modems** *•••• Cable Modems <i>•••* cost, noise and efficiency. The adaptive, non-**•• Set-Top Boxes/ Home Gateways ••• Integral overlapping MOSFET** gate-drivers and high-side
 ••• bootstrap structure helps to further maximize **bootstrap Structure helps to further maximize**
• efficiency. The high-side power FET drain voltage can
• **PDR** Corean efficiency. The high-side power FET drain voltage can be from 1V to 16V and the output voltage is

TYPICAL APPLICATION

Figure 1. Typical Application Circuit

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

CONNECTION DIAGRAM

Figure 2. 14-Lead Plastic TSSOP θJA = 155°C/W

PIN DESCRIPTIONS

BOOT (Pin 1) - Supply rail for the N-channel MOSFET gate drive. The voltage should be at least one gate threshold above the regulator input voltage to properly turn on the high-side N-FET.

LG (Pin 2) - Gate drive for the low-side N-channel MOSFET. This signal is interlocked with HG to avoid shootthrough problems

PGND (Pins 3, 13) - Ground for FET drive circuitry. It should be connected to system ground.

SGND (Pin 4) - Ground for signal level circuitry. It should be connected to system ground.

V_{CC} (Pin 5) - Supply rail for the controller.

PWGD (Pin 6) - Power Good. This is an open drain output. The pin is pulled low when the chip is in UVP, OVP, or UVLO mode. During normal operation, this pin is connected to V_{CC} or other voltage source through a pull-up resistor.

ISEN (Pin 7) - Current limit threshold setting. This sources a fixed 50µA current. A resistor of appropriate value should be connected between this pin and the drain of the low-side FET.

EAO (Pin 8) - Output of the error amplifier. The voltage level on this pin is compared with an internally generated ramp signal to determine the duty cycle. This pin is necessary for compensating the control loop.

SS (Pin 9) - Soft start pin. A capacitor connected between this pin and ground sets the speed at which the output voltage ramps up. Larger capacitor value results in slower output voltage ramp but also lower inrush current.

FB (Pin 10) - This is the inverting input of the error amplifier, which is used for sensing the output voltage and compensating the control loop.

FREQ (Pin 11) - The switching frequency is set by connecting a resistor between this pin and ground.

SD (Pin 12) - IC Logic Shutdown. When this pin is pulled low the chip turns off both the high side and low side switches. While this pin is low, the IC will not start up. An internal 20 μ A pull-up connects this pin to V_{CC}. For a device which turns on the low side switch during shutdown, see the pin compatible LM2737.

HG (Pin 14) - Gate drive for the high-side N-channel MOSFET. This signal is interlocked with LG to avoid shootthrough problems.

ABSOLUTE MAXIMUM RATINGS (1)

If Military/Aerospace specified devices are required, contact the Texas Instruments Semiconductor Sales Office/ Distributors for availability and specifications.

(1) Absolute maximum ratings indicate limits beyond which damage to the device may occur. **Operating ratings** indicate conditions for which the device operates correctly. **Operating Ratings** do **not imply** ensured performance limits.

(2) The LG and HG pin can have -2V to -0.5V applied for a maximum duty cycle of 10% with a maximum period of 1 second. There is no duty cycle or maximum period limitation for a LG and HG pin voltage range of -0.5V to 21V.

RECOMMENDED OPERATING CONDITIONS

ELECTRICAL CHARACTERISTICS

 $\rm V_{CC}$ = 5V unless otherwise indicated. Typicals and limits appearing in plain type apply for T_A=T_J=+25°C. Limits appearing in boldface type apply over full Operating Temperature Range. Datasheet min/max specification limits are specified by design, test, or statistical analysis.

ELECTRICAL CHARACTERISTICS (continued)

 $\rm V_{CC}$ = 5V unless otherwise indicated. Typicals and limits appearing in plain type apply for T_A=T_J=+25°C. Limits appearing in boldface type apply over full Operating Temperature Range. Datasheet min/max specification limits are specified by design, test, or statistical analysis.

Bootpin Current vs Temperature with 5V Bootstrap PWM Frequency vs Temperature
F_{SW} = 600kHz, Si4826DY FET, No-Load for R_{FADJ} = 43.2kΩ

VCC Operating Current vs Temperature Bootpin Current vs Temperature for BOOTV = 12V FSW = 600kHz, No-Load FSW = 600kHz, Si4826DY FET, No-Load

RF-ADJ (kΩ)

V_{CC} PLUS BOOT CURRENT

RF-ADJ (KΩ)

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Figure 17. Figure 18.

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20 μ s/DIV

Figure 21. Figure 22.

40 μ s/DIV **Figure 23. Figure 24.**

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BLOCK DIAGRAM

APPLICATION INFORMATION

THEORY OF OPERATION

The LM2742 is a voltage-mode, high-speed synchronous buck regulator with a PWM control scheme. It is designed for use in set-top boxes, thin clients, DSL/Cable modems, and other applications that require high efficiency buck converters. It has power good (PWRGD), and output shutdown (SD). Current limit is achieved by sensing the voltage V_{DS} across the low side FET. During current limit the high side gate is turned off and the low side gate turned on. The soft start capacitor is discharged by a 95µA source (reducing the maximum duty cycle) until the current is under control.

START UP

When V_{CC} exceeds 4.2V and the shutdown pin \overline{SD} sees a logic high the soft start capacitor begins charging through an internal fixed 10µA source. During this time the output of the error amplifier is allowed to rise with the voltage of the soft start capacitor. This capacitor, C_{SS} , determines soft start time, and can be determined approximately by:

$$
C_{ss} = \frac{t_{ss}}{2.5 \times 10^5}
$$
 (1)

An application for a microprocessor might need a delay of 3ms, in which case C_{SS} would be 12nF. For a different device, a 100ms delay might be more appropriate, in which case C_{SS} would be 400nF. (390 10%) During soft start the PWRGD flag is forced low and is released when the voltage reaches a set value. At this point this chip enters normal operation mode and the Power Good flag is released.

Since the output is floating when the LM2742 is turned off, it is possible that the output capacitor may be precharged to some positive value. During start-up, the LM2742 operates fully synchronous and will discharge the output capacitor to some extent depending on the output voltage, soft start capacitance, and the size of the output capacitor.

NORMAL OPERATION

While in normal operation mode, the LM2742 regulates the output voltage by controlling the duty cycle of the high side and low side FETs. The equation governing output voltage is:

$$
V_0 = 0.6 \times (R_{FB1} + R_{FB2}) / R_{FB1}
$$
 (2)

1.0526

The PWM frequency is adjustable between 50kHz and 2MHz and is set by an external resistor, R_{FADJ} , between the FREQ pin and ground. The resistance needed for a desired frequency is approximately:

$$
R_{FADJ} = \left(\frac{20500}{\text{freq}[kHz]}\right)^{1.0526} k\Omega
$$

MOSFET GATE DRIVERS

The LM2742 has two gate drivers designed for driving N-channel MOSFETs in a synchronous mode. Power for the drivers is supplied through the BOOT pin. For the high side gate (HG) to fully turn on the top FET, the BOOT voltage must be at least one V_{GS(th)} greater than Vin. (BOOT $\geq 2^{*}$ Vin) This voltage can be supplied by a separate, higher voltage source, or supplied from a local charge pump structure. In a system such as a desktop computer, both 5V and 12V are usually available. Hence if Vin was 5V, the 12V supply could be used for BOOT. 12V is more than 2*Vin, so the HG would operate correctly. For a BOOT of 12V, the initial gate charging current is 2A, and the initial gate discharging current is typically 6A.

(3)

Figure 29. BOOT Supplied by Charge Pump

In a system without a separate, higher voltage, a charge pump (bootstrap) can be built using a diode and small capacitor, [Figure](#page-12-0) 29. The capacitor serves to maintain enough voltage between the top FET gate and source to control the device even when the top FET is on and its source has risen up to the input voltage level.

The LM2742 gate drives use a BiCMOS design. Unlike some other bipolar control ICs, the gate drivers have railto-rail swing, ensuring no spurious turn-on due to capacitive coupling.

POWER GOOD SIGNAL

The power good signal is the or-gated flag representing over-voltage and under-voltage protection. If the output voltage is 18% over it's nominal value, $V_{FB} = 0.7V$, or falls 30% below that value, $V_{FB} = 0.41V$, the power good flag goes low. It will return to a logic high whenever the feedback pin voltage is between 70% and 118% of 0.6V. The power good pin is an open drain output that can be pulled up to logic voltages of 5V or less with a 10kΩ resistor.

UVLO

The 4.2V turn-on threshold on V_{CC} has a built in hysteresis of 0.6V. Therefore, if V_{CC} drops below 3.6V, the chip enters UVLO mode. UVLO consists of turning off the top FET, turning off the bottom FET, and remaining in that condition until V_{CC} rises above 4.2V. As with shutdown, the soft start capacitor is discharged through a FET, ensuring that the next start-up will be smooth.

CURRENT LIMIT

Current limit is realized by sensing the voltage across the low side FET while it is on. The R_{DSON} of the FET is a known value, hence the current through the FET can be determined as:

$$
V_{DS} = I^* R_{DSON} \tag{4}
$$

The current through the low side FET while it is on is also the falling portion of the triangle wave inductor current. The current limit threshold is determined by an external resistor, R_{CS} , connected between the switch node and the $I_{\rm SEN}$ pin. A constant current of 50 µA is forced through R_{CS}, causing a fixed voltage drop. This fixed voltage is compared against V_{DS} and if the latter is higher, the current limit of the chip has been reached. R_{CS} can be found by using the following equation:

$$
R_{CS} = R_{DSON}(LOW)^* I_{LIM}/50\mu A
$$
 (5)

For example, a conservative 15A current limit in a 10A design with a minimum R_{DSON} of 10mΩ would require a 3.3kΩ resistor. Because current sensing is done across the low side FET, no minimum high side on-time is necessary. In the current limit mode the LM2727/37 will turn the high side off and the keep low side on for as long as necessary. The LM2727/37 enters current limit mode if the inductor current exceeds the current limit threshold at the point where the high side FET turns off and the low side FET turns on. (The point of peak inductor current. See [Figure](#page-13-0) 30.) Note that in normal operation mode the high side FET always turns on at the

beginning of a clock cycle. In current limit mode, by contrast, the high side FET on pulse is skipped. This causes inductor current to fall. Unlike a normal operation switching cycle, however, in a current limit mode switching cycle the high side FET will turn on as soon as inductor current has fallen to the current limit threshold. The LM2727/37 will continue to skip high side FET pulses until the inductor current peak is below the current limit threshold, at which point the system resumes normal operation.

Figure 30. Current Limit Threshold

Unlike a high side FET current sensing scheme, which limits the peaks of inductor current, low side current sensing is only allowed to limit the current during the converter off-time, when inductor current is falling. Therefore in a typical current limit plot the valleys are normally well defined, but the peaks are variable, according to the duty cycle. The PWM error amplifier and comparator control the off pulse of the high side FET, even during current limit mode, meaning that peak inductor current can exceed the current limit threshold. Assuming that the output inductor does not saturate, the maximum peak inductor current during current limit mode can be calculated with the following equation:

$$
I_{PK-CL} = I_{LIM} + (T_{OSC} - 200 \text{ ns}) \frac{V_{IN} - V_{O}}{L}
$$

(6)

Where T_{OSC} is the inverse of switching frequency f_{OSC}. The 200ns term represents the minimum off-time of the duty cycle, which ensures enough time for correct operation of the current sensing circuitry. See the plots entitled Peak Current During Current Limit in the Typical Performance Characteristics section.

In order to minimize the time period in which peak inductor current exceeds the current limit threshold, the IC also discharges the soft start capacitor through a fixed 95 µA source. The output of the LM2727/37 internal error amplifier is limited by the voltage on the soft start capacitor. Hence, discharging the soft start capacitor reduces the maximum duty cycle D of the controller. During severe current limit this reduction in duty cycle will reduce the output voltage if the current limit conditions last for an extended time. Output inductor current will be reduced in turn to a flat level equal to the current limit threshold. The third benefit of the soft start capacitor discharge is a smooth, controlled ramp of output voltage when the current limit condition is cleared. During the first few nanoseconds after the low side gate turns on, the low side FET body diode conducts. This causes an additional 0.7V drop in V_{DS}. The range of V_{DS} is normally much lower. For example, if R_{DSON} were 10mΩ and the current through the FET was 10A, V_{DS} would be 0.1V. The current limit would see 0.7V as a 70A current and enter current limit immediately. Hence current limit is masked during the time it takes for the high side switch to turn off and the low side switch to turn on.

SHUT DOWN

If the shutdown pin \overline{SD} is pulled low, the LM2742 discharges the soft start capacitor through a MOSFET switch. The high side and low side switches are turned off. The LM2742 remains in this state until SD is released.

DESIGN CONSIDERATIONS

The following is a design procedure for all the components needed to create the circuit shown in [Figure](#page-18-0) 32 in the Example Circuits section, a 5V in to 1.2V out converter, capable of delivering 10A with an efficiency of 85%. The switching frequency is 300kHz. The same procedures can be followed to create many other designs with varying input voltages, output voltages, and output currents.

Input Capacitor

The input capacitors in a Buck switching converter are subjected to high stress due to the input current waveform, which is a square wave. Hence input caps are selected for their ripple current capability and their ability to withstand the heat generated as that ripple current runs through their ESR. Input rms ripple current is approximately:

$$
I_{\rm rms_rip} = I_0 \sqrt{\frac{1}{2} \left(1 - D\right)} \tag{7}
$$

The power dissipated by each input capacitor is:

$$
P_D = \frac{I_{\text{rms} - rip}^2 * ESR}{n^2}
$$
 (8)

Here, n is the number of capacitors, and indicates that power loss in each cap decreases rapidly as the number of input caps increase. The worst-case ripple for a Buck converter occurs during full load, when the duty cycle D $= 50\%$.

In the 5V to 1.2V case, $D = 1.2/5 = 0.24$. With a 10A maximum load the ripple current is 4.3A. The Sanyo 10MV5600AX aluminum electrolytic capacitor has a ripple current rating of 2.35A, up to 105°C. Two such capacitors make a conservative design that allows for unequal current sharing between individual caps. Each capacitor has a maximum ESR of 18mΩ at 100 kHz. Power loss in each device is then 0.05W, and total loss is 0.1W. Other possibilities for input and output capacitors include MLCC, tantalum, OSCON, SP, and POSCAPS.

Input Inductor

The input inductor serves two basic purposes. First, in high power applications, the input inductor helps insulate the input power supply from switching noise. This is especially important if other switching converters draw current from the same supply. Noise at high frequency, such as that developed by the LM2742 at 1MHz operation, could pass through the input stage of a slower converter, contaminating and possibly interfering with its operation.

An input inductor also helps shield the LM2742 from high frequency noise generated by other switching converters. The second purpose of the input inductor is to limit the input current slew rate. During a change from no-load to full-load, the input inductor sees the highest voltage change across it, equal to the full load current times the input capacitor ESR. This value divided by the maximum allowable input current slew rate gives the minimum input inductance:

$$
L_{in} = \frac{\Delta V}{\left(\frac{di}{dt}\right)_{max}}
$$
(9)

In the case of a desktop computer system, the input current slew rate is the system power supply or "silver box" output current slew rate, which is typically about 0.1A/µs. Total input capacitor ESR is 9mΩ, hence ΔV is 10*0.009 = 90 mV, and the minimum inductance required is 0.9µH. The input inductor should be rated to handle the DC input current, which is approximated by:

$$
I_{IN-DC} = \frac{I_O * D}{\eta}
$$
 (10)

In this case $I_{\text{IN-DC}}$ is about 2.8A. One possible choice is the TDK SLF12575T-1R2N8R2, a 1.2µH device that can handle 8.2Arms, and has a DCR of 7mΩ.

Output Inductor

The output inductor forms the first half of the power stage in a Buck converter. It is responsible for smoothing the square wave created by the switching action and for controlling the output current ripple. (Δl_o) The inductance is chosen by selecting between tradeoffs in output ripple, efficiency, and response time. The smaller the output inductor, the more quickly the converter can respond to transients in the load current. If the inductor value is increased, the ripple through the output capacitor is reduced and thus the output ripple is reduced. As shown in the efficiency calculations, a smaller inductor requires a higher switching frequency to maintain the same level of output current ripple. An increase in frequency can mean increasing loss in the FETs due to the charging and discharging of the gates. Generally the switching frequency is chosen so that conduction loss outweighs switching loss. The equation for output inductor selection is:

$$
L = \frac{V_{\text{in}} - V_0}{\Delta i_0 * F_{\text{SW}}}
$$
 (11)

A good range for $Δl_o$ is 25 to 50% of the output current. In the past, 30% was considered a maximum value for output currents higher than about 2Amps, but as output capacitor technology improves the ripple current can be allowed to increase. Plugging in the values for output current ripple, input voltage, output voltage, switching frequency, and assuming a 40% peak-to-peak output current ripple yields an inductance of 1.5µH. The output inductor must be rated to handle the peak current (also equal to the peak switch current), which is (lo + 0.5* Δ l_o). This is 12A for a 10A design. The Coilcraft D05022-152HC is 1.5µH, is rated to 15Arms, and has a DCR of 4mΩ.

Output Capacitor

The output capacitor forms the second half of the power stage of a Buck switching converter. It is used to control the output voltage ripple (ΔV_o) and to supply load current during fast load transients.

In this example the output current is 10A and the expected type of capacitor is an aluminum electrolytic, as with the input capacitors. (Other possibilities include ceramic, tantalum, and solid electrolyte capacitors, however the ceramic type often do not have the large capacitance needed to supply current for load transients, and tantalums tend to be more expensive than aluminum electrolytic.) Aluminum capacitors tend to have very high capacitance and fairly low ESR, meaning that the ESR zero, which affects system stability, will be much lower than the switching frequency. The large capacitance means that at switching frequency, the ESR is dominant, hence the type and number of output capacitors is selected on the basis of ESR. One simple formula to find the maximum ESR based on the desired output voltage ripple, ΔV_0 and the designed output current ripple, ΔI_0 , is:

$$
ESR_{MAX} = \frac{\Delta V_o}{\Delta l_o}
$$
 (12)

In this example, in order to maintain a 2% peak-to-peak output voltage ripple and a 40% peak-to-peak inductor current ripple, the required maximum ESR is 6mΩ. Three Sanyo 10MV5600AX capacitors in parallel will give an equivalent ESR of 6mΩ. The total bulk capacitance of 16.8mF is enough to supply even severe load transients. Using the same capacitors for both input and output also keeps the bill of materials simple.

MOSFETS

MOSFETS are a critical part of any switching controller and have a direct impact on the system efficiency. In this case the target efficiency is 85% and this is the variable that will determine which devices are acceptable. Loss from the capacitors, inductors, and the LM2742 is detailed in the Efficiency section, and come to about 0.54W. To meet the target efficiency, this leaves 1.45W for the FET conduction loss, gate charging loss, and switching loss. Switching loss is particularly difficult to estimate because it depends on many factors. When the load current is more than about 1 or 2 amps, conduction losses outweigh the switching and gate charging losses. This allows FET selection based on the R_{DSON} of the FET. Adding the FET switching and gate-charging losses to the equation leaves 1.2W for conduction losses. The equation for conduction loss is:

$$
P_{\text{Cnd}} = D(I_{o}^{2} * R_{\text{DSON}} * k) + (1-D)(I_{o}^{2} * R_{\text{DSON}} * k)
$$
\n(13)

The factor k is a constant which is added to account for the increasing R_{DSON} of a FET due to heating. Here, k = 1.3. The Si4442DY has a typical R_{DSON} of 4.1mΩ. When plugged into the equation for P_{CND} the result is a loss of 0.533W. If this design were for a 5V to 2.5V circuit, an equal number of FETs on the high and low sides would be the best solution. With the duty cycle $D = 0.24$, it becomes apparent that the low side FET carries the load current 76% of the time. Adding a second FET in parallel to the bottom FET could improve the efficiency by lowering the effective R_{DSON} . The lower the duty cycle, the more effective a second or even third FET can be. For a minimal increase in gate charging loss (0.054W) the decrease in conduction loss is 0.15W. What was an 85% design improves to 86% for the added cost of one SO-8 MOSFET.

Control Loop Components

The circuit is this design example and the others shown in the Example Circuits section have been compensated to improve their DC gain and bandwidth. The result of this compensation is better line and load transient responses. For the LM2742, the top feedback divider resistor, Rfb2, is also a part of the compensation. For the 10A, 5V to 1.2V design, the values are:

Cc1 = 4.7pF 10%, Cc2 = 1nF 10%, Rc = 229kΩ 1%. These values give a phase margin of 63° and a bandwidth of 29.3kHz.

Support Capacitors and Resistors

The Cinx capacitors are high frequency bypass devices, designed to filter harmonics of the switching frequency and input noise. Two 1µF ceramic capacitors with a sufficient voltage rating (10V for the Circuit of [Figure](#page-18-0) 32) will work well in almost any case.

 R_{IN} and C_{IN} are standard filter components designed to ensure smooth DC voltage for the chip supply. Depending on noise, R_{IN} should be 10 to 100 Ω , and C_{IN} should be between 0.1 and 2.2 µF. C_{BOOT} is the bootstrap capacitor, and should be 0.1µF. (In the case of a separate, higher supply to the BOOT pin, this 0.1µF cap can be used to bypass the supply.) Using a Schottky device for the bootstrap diode allows the minimum drop for both high and low side drivers. The On Semiconductor BAT54 or MBR0520 work well.

Rp is a standard pull-up resistor for the open-drain power good signal, and should be 10kΩ. If this feature is not necessary, it can be omitted.

 R_{CS} is the resistor used to set the current limit. Since the design calls for a peak current magnitude (Io + 0.5 * ΔI_o) of 12A, a safe setting would be 15A. (This is well below the saturation current of the output inductor, which is 25A.) Following the equation from the Current Limit section, use a 3.3k Ω resistor.

 $R_{FAD,J}$ is used to set the switching frequency of the chip. Following the equation in the Theory of Operation section, the closest 1% tolerance resistor to obtain $f_{SW} = 300$ kHz is 88.7k Ω .

 C_{SS} depends on the users requirements. Based on the equation for C_{SS} in the Theory of Operation section, for a 3ms delay, a 12nF capacitor will suffice.

EFFICIENCY CALCULATIONS

A reasonable estimation of the efficiency of a switching controller can be obtained by adding together the loss is each current carrying element and using the equation:

$$
\eta = \frac{P_o}{P_o + P_{total-loss}}\tag{14}
$$

The following shows an efficiency calculation to complement the Circuit of [Figure](#page-18-0) 32. Output power for this circuit is 1.2V x 10A = 12W.

Chip Operating Loss

 $P_{IQ} = I_{Q\text{-}Vcc}$ * V_{CC} (15) $2mA \times 5V = 0.01W$

FET Gate Charging Loss

$$
P_{GC} = n \cdot V_{CC} \cdot Q_{GS} \cdot f_{OSC} \tag{16}
$$

The value n is the total number of FETs used. The Si4442DY has a typical total gate charge, Q_{GS} , of 36nC and an r_{ds-on} of 4.1mΩ. For a single FET on top and bottom: $2*5*36E^{9*}300,000 = 0.108W$

FET Switching Loss

 $P_{SW} = 0.5 * V_{in} * I_0 * (t_r + t_f) * f_{OSC}$ $)^*$ f_{OSC} (17)

The Si4442DY has a typical rise time t_r and fall time t_f of 11 and 47ns, respectively. 0.5*5*10*58E^{-9*}300,000 = 0.435W

(24)

$$
P_{\text{Lout}} = I^2 \cdot \text{DCR}_{\text{output-L}}
$$

 $10^{2*}0.004 = 0.4W$

System Efficiency

$$
\frac{12}{22+1.7}=87.5\%
$$

Example Circuits

Figure 31. 5V-16V to 3.3V, 10A, 300kHz

This circuit and the one featured on the front page have been designed to deliver high current and high efficiency in a small package, both in area and in height The tallest component in this circuit is the inductor L1, which is 6mm tall. The compensation has been designed to tolerate input voltages from 5 to 16V.

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Figure 32. 5V to 1.2V, 10A, 300kHz

This circuit design, detailed in the Design Considerations section, uses inexpensive aluminum capacitors and offthe-shelf inductors. It can deliver 10A at better than 85% efficiency. Large bulk capacitance on input and output ensure stable operation.

The example circuit of [Figure](#page-18-1) 33 has been designed for minimum component count and overall solution size. A switching frequency of 600kHz allows the use of small input/output capacitors and a small inductor. The availability of separate 5V and 12V supplies (such as those available from desk-top computer supplies) and the low current further reduce component count. Using the 12V supply to power the MOSFET drivers eliminates the bootstrap diode, D1. At low currents, smaller FETs or dual FETs are often the most efficient solutions. Here, the Si4826DY, an asymmetric dual FET in an SO-8 package, yields 92% efficiency at a load of 2A.

Figure 34. 3.3V to 0.8V, 5A, 500kHz

The circuit of [Figure](#page-19-0) 34 demonstrates the LM2742 delivering a low output voltage at high efficiency (87%). A separate 5V supply is required to run the chip, however the input voltage can be as low as 2.2

Figure 35. 1.8V and 3.3V, 1A, 1.4MHz, Simultaneous

The circuits in [Figure](#page-19-1) 35 are intended for ADSL applications, where the high switching frequency keeps noise out of the data transmission range. In this design, the 1.8 and 3.3V outputs come up simultaneously by using the same softstart capacitor. Because two current sources now charge the same capacitor, the capacitance must be doubled to achieve the same softstart time. (Here, 40nF is used to achieve a 5ms softstart time.) A common softstart capacitor means that, should one circuit enter current limit, the other circuit will also enter current limit. The additional compensation components Rc2 and Cc3 are needed for the low ESR, all ceramic output capacitors, and the wide (3x) range of Vin.

Figure 36. 12V Unregulated to 3.3V, 3A, 750kHz

This circuit shows the LM2742 paired with a cost effective solution to provide the 5V chip power supply, using no extra components other than the LM78L05 regulator itself. The input voltage comes from a 'brick' power supply which does not regulate the 12V line tightly. Additional, inexpensive 10uF ceramic capacitors (Cinx and Cox) help isolate devices with sensitive databands, such as DSL and cable modems, from switching noise and harmonics.

Figure 37. 12V to 5V, 1.8A, 100kHz

In situations where low cost is very important, the LM2742 can also be used as an asynchronous controller, as shown in the above circuit. Although a a schottky diode in place of the bottom FET will not be as efficient, it will cost much less than the FET. The 5V at low current needed to run the LM2742 could come from a zener diode or inexpensive regulator, such as the one shown in [Figure](#page-20-0) 36. Because the LM2742 senses current in the low side MOSFET, the current limit feature will not function in an asynchronous design. The ISEN pin should be left open in this case.

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Table 1. Bill of Materials for Typical Application Circuit [\(Figure](#page-0-0) 1)

Table 2. Bill of Materials for Circuit of [Figure](#page-17-0) 31 (Identical to BOM for 1.5V except as noted below)

Table 3. Bill of Materials for Circuit of [Figure](#page-18-0) 32

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Table 3. Bill of Materials for Circuit of [Figure](#page-18-0) 32 (continued)

Table 4. Bill of Materials for Circuit of [Figure](#page-18-1) 33

Table 5. Bill of Materials for Circuit of [Figure](#page-19-0) 34

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Table 6. Bill of Materials for Circuit of [Figure](#page-19-1) 35

Table 7. Bill of Materials for 3.3V Circuit of [Figure](#page-19-1) 35 (Identical to BOM for 1.8V except as noted below)

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Table 8. Bill of Materials for Circuit of [Figure](#page-20-0) 36

Table 9. Bill of Materials for Circuit of [Figure](#page-20-1) 37

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PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

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LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

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Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

TEXAS

TAPE AND REEL INFORMATION

ISTRUMENTS

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

TEXAS INSTRUMENTS

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TUBE

B - Alignment groove width

*All dimensions are nominal

PACKAGE OUTLINE

PW0014A TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0014A TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.

^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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